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# Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

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# STC08DE150HV

Hybrid emitter switched bipolar transistor ESBT® 1500 V - 8 A - 0.075  $\Omega$ 

#### **Features**

V <sub>CS(ON)</sub>	I <sub>C</sub>	R <sub>CS(ON)</sub>
0.6 V	8 A	$0.075~\Omega$

■ Low equivalent ON resistance

■ Very fast-switch: up to 150 kHz

■ Squared RBSOA: up to 1500 V

■ Very low  $C_{ISS}$  driven by  $R_G = 47 \Omega$ 

### **Application**

Single switch SMPS based on three-phase mains

#### **Description**

The STC08DE150HV is manufactured in a hybrid structure, using dedicated high voltage bipolar and low voltage MOSESS technologies, aimed at providing the best performance in an ESBT topology.

The STC0 จีบิธีวิ50HV is designed for use in auxilia ry fryback SMPS for any three-phase ละเมื่อสมดก.

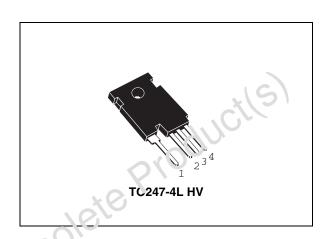


Figure 1. Internal schematic diagrams

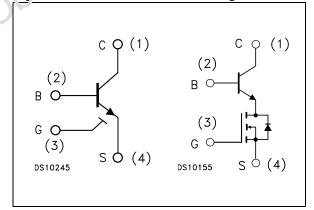


Table 1. Device summary

Order code	Marking	Package	Packing	
STC08DE150HV	C08DE150HV	TO247-4L HV	Tube	

Electrical ratings STC08DE150HV

# 1 Electrical ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V <sub>CS(SS)</sub>	Collector-source voltage (V <sub>BS</sub> = V <sub>GS</sub> = 0)	1500	V
V <sub>BS(OS)</sub>	Base-source voltage ( $I_C = 0$ , $V_{GS} = 0$ )	30	V
V <sub>SB(OS)</sub>	Source-base voltage ( $I_C = 0$ , $V_{GS} = 0$ )	9	٧
V <sub>GS</sub>	Gate-source voltage	±20	٧
I <sub>C</sub>	Collector current	8	A
I <sub>CM</sub>	Collector peak current (t <sub>P</sub> < 5 ms)	15	Α
I <sub>B</sub>	Base current	8	Α
I <sub>BM</sub>	Base peak current (t <sub>P</sub> < 1 ms)	15	Α
P <sub>tot</sub>	Total dissipation at $T_c \le 25$ °C	156	W
T <sub>stg</sub>	Storage temperature	-40 to 150	°C
T <sub>J</sub>	Max. operating junction temperature	125	ç

Table 3. Thermal data

Symbol	l'arameter	Value	Unit
R <sub>thJC</sub>	Thermal resistance junction-case	0.64	°C/W
	10010.		
*e,Y			
Olejo			
0050			

## 2 Electrical characteristics

(T<sub>case</sub> = 25°C unless otherwise specified)

Table 4. Electrical characteristics

0						
Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I <sub>CS(SS)</sub>	Collector cut-off current (V <sub>BS</sub> = V <sub>GS</sub> = 0)	V <sub>CS</sub> = 1500 V			100	μΑ
I <sub>BS(OS)</sub>	Base cut-off current $(I_C = 0, V_{GS} = 0)$	V <sub>BS</sub> = 30 V			10	μA
I <sub>SB(OS)</sub>	Source cut-off current $(I_C = 0, V_{GS} = 0)$	V <sub>SB</sub> = 9 V		( )C	100	μA
I <sub>GS(OS)</sub>	Gate-source leakage current (V <sub>BS</sub> = 0)	V <sub>GS</sub> = ± 20 V	(0)		500	nA
V <sub>CS(ON)</sub>	Collector-source ON voltage	$V_{GS} = 10 \text{ V}$ $I_C = 8 \text{ A}$ $I_B = 1.6 \text{ A}$ $V_{GS} = 10 \text{ V}$ $I_C = 5 \text{ A}$ $I_{L'} = 0.5 \text{ A}$		0.6 0.6	1.4	V V
h <sub>FE</sub> <sup>(1)</sup>	DC current gain	$I_C = 8 \text{ A}$ $V_{CS} = 1 \text{ V}$ $V_{GS} = 10 \text{ V}$ $I_C = 5 \text{ A}$ $V_{CC} = 1 \text{ V}$ $V_{GS} = 10 \text{ V}$	4.5 8	7.5 10		
V <sub>BS(ON)</sub>	Base-source ON voltage	V <sub>GS</sub> = 10 V I <sub>C</sub> = 8 A I <sub>B</sub> = 1.6 A V <sub>GS</sub> = 10 V I <sub>C</sub> = 5 A I <sub>B</sub> = 0.5 A		1.5 1	2	V V
V <sub>GS(th)</sub>	Gate threshold voltage	$V_{BS} = V_{GS}$ $I_B = 250 \mu A$	1.5	2.2	3	V
C <sub>iss</sub>	Input capacitance (V <sub>GS</sub> = V <sub>CB</sub> = 0)	V <sub>CS</sub> = 25 V f = 1 MHz		750		pF
Q <sub>GS(tot)</sub>	Gate-cource charge	V <sub>GS</sub> = 10 V I <sub>C</sub> = 8 A V <sub>CS</sub> = 25 V		12.5		nC
iç t <sub>f</sub>	Inductive load Storage time Fall time	$\begin{aligned} & V_{GS} = 10 \ V & R_G = 47 \ \Omega \\ & V_{Clamp} = 1200 \ V & t_p = 4 \ \mu s \\ & I_C = 5 \ A & I_B = 0.5 \ A \end{aligned}$		526 8.5		ns ns
t <sub>f</sub> t <sub>f</sub>	Inductive load Storage time Fall time	$\begin{aligned} &V_{GS} = 10 \text{ V} & R_G = 47 \ \Omega \\ &V_{Clamp} = 1200 \text{ V} & t_p = 4 \ \mu s \\ &I_C = 5 \text{ A} & I_B = 1 \text{ A} \end{aligned}$		884 16		ns ns
V <sub>CSW</sub>	Maximum collector- source voltage at turn- off without snubber	$R_G = 47 \Omega$ $h_{FE} = 5$ $I_C = 8 A$	1500			V
V <sub>CS(dyn)</sub>	Collector-source dynamic voltage (0.5 µs)	$\begin{split} &V_{CC} = V_{Clamp} = 300 \ V \\ &V_{GS} = 10 \ V & I_{C} = 4 \ A \\ &I_{B} = 0.8 \ A & t_{peak} = 500 \ ns \\ &R_{G} = 47 \ \Omega & I_{Bpeak} = 8 \ A \ (2I_{C}) \end{split}$		6		V
V <sub>CS(dyn)</sub>	Collector-source dynamic voltage (1 µs)	$V_{CC} = V_{Clamp} = 300 \text{ V}$ $V_{GS} = 10 \text{ V}$ $I_{C} = 4 \text{ A}$ $I_{B} = 0.8 \text{ A}$ $I_{peak} = 500 \text{ns}$ $R_{G} = 47 \Omega$ $I_{Bpeak} = 8 \text{ A} (2I_{C})$		2.2		٧

<sup>1.</sup> Pulsed duration = 300 µs, duty cycle ≤ 1.5%

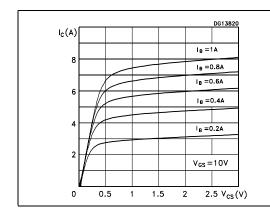


Electrical characteristics STC08DE150HV

#### 2.1 Electrical characteristics (curves)

Figure 2. Output characteristics

Figure 3. Collector-source dynamic voltage



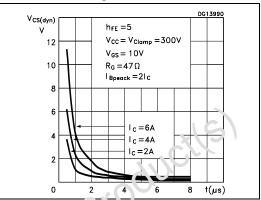
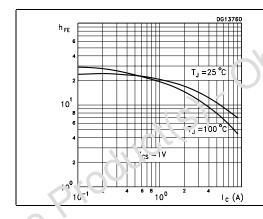


Figure 4. DC current gain

Figure 5. Gate threshold voltage vs. temperature



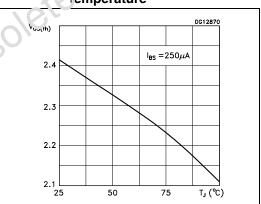
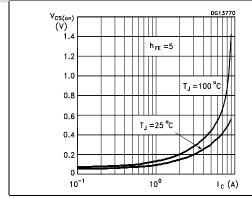
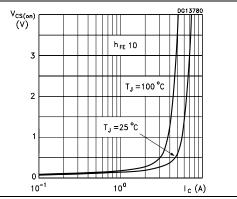


Figure 6. Collector-source ON voltage Figure 7. (h<sub>FE</sub> = 5)

Figure 7. Collector-source ON voltage  $(h_{FE} = 10)$ 





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Figure 8. Base-source ON voltage  $(h_{FE} = 5)$ 

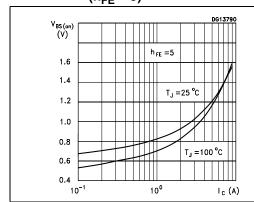


Figure 9. Base-source ON voltage  $(h_{FE} = 10)$ 

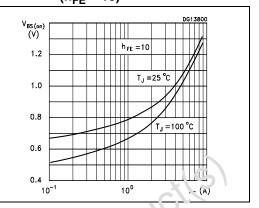
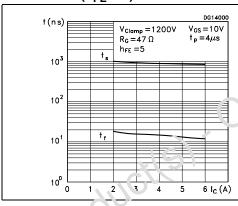


Figure 10. Inductive load switching time Figure 11. Inductive 'occ switching time  $(h_{FE} = 5)$   $(h_{FE} = 10)$ 



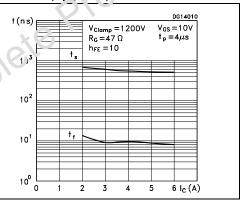
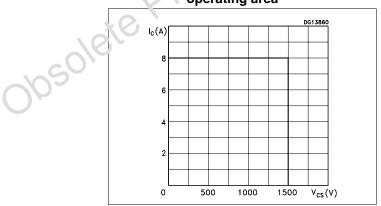


Figure 12. Reverse biased safe operating area



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## 3 Package mechanical data

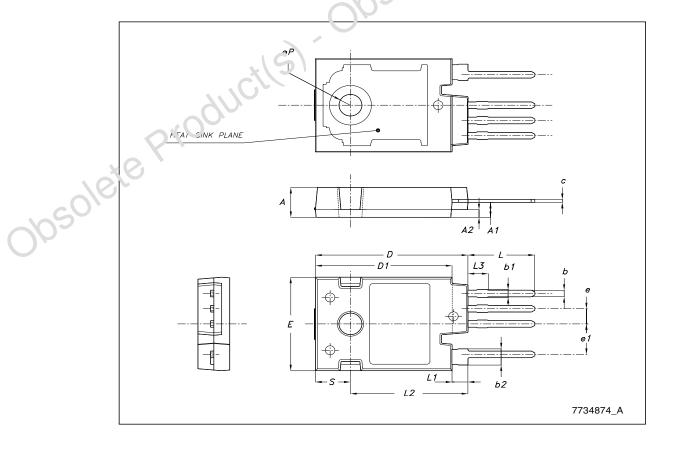
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#### TO247-4L HV mechanical data

DIM.		mm.	
DIWI.	MIN.	TYP	MAX.
Α	4.85		5.15
A1	2.20	2.50	2.60
A2		1.27	
b	0.95	1.10	1.30
b1	1.10		1.50
b2	2.50		2.90
С	0.40		0.80
D	23.85	24	24.15
D1		21.50	C
E	15.45	15.60	15:75
е		2.54	
e1		5.08	()
L	10.20	100	10.80
L1	2.20	2.50	2.80
L2		18.5C	
L3		3	
øΡ	3.55		3.65
S		5.50	



Revision history STC08DE150HV

# 4 Revision history

Table 5. Document revision history

Date	Revision	Changes
25-Oct-2006	1	First release.
17-Jun-2009	2	Document status promoted from preliminary data to datasheet.



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